Hanno Küpers

List of Publications by Year in descending order

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840776 839539 19 308 11 18 citations h-index g-index papers 19 19 19 396 docs citations times ranked citing authors all docs

| # | Article | IF | Citations |
|----|--|------|-----------|
| 1 | Drastic Effect of Sequential Deposition Resulting from Flux Directionality on the Luminescence Efficiency of Nanowire Shells. ACS Applied Materials & Samp; Interfaces, 2021, 13, 50220-50227. | 8.0 | 1 |
| 2 | Predictive model for the temporal evolution of the shape of GaAs nanowires. Journal of Crystal Growth, 2020, 531, 125320. | 1.5 | 0 |
| 3 | Spatially-resolved luminescence and crystal structure of single core–shell nanowires measured in the as-grown geometry. Nanotechnology, 2020, 31, 214002. | 2.6 | 3 |
| 4 | Impact of the Shadowing Effect on the Crystal Structure of Patterned Self-Catalyzed GaAs Nanowires. Nano Letters, 2019, 19, 4263-4271. | 9.1 | 17 |
| 5 | Impact of Outer Shell Structure and Localization Effects on Charge Carrier Dynamics in GaAs/(In,Ga)As Nanowire Core–Shell Quantum Wells. Physica Status Solidi - Rapid Research Letters, 2019, 13, 1800527. | 2.4 | 7 |
| 6 | Diameter evolution of selective area grown Ga-assisted GaAs nanowires. Nano Research, 2018, 11, 2885-2893. | 10.4 | 38 |
| 7 | Nanowires Bending over Backward from Strain Partitioning in Asymmetric Core–Shell Heterostructures. Nano Letters, 2018, 18, 2343-2350. | 9.1 | 35 |
| 8 | Complete structural and strain analysis of single GaAs/(In,Ga)As/GaAs core–shell–shell nanowires by means of in-plane and out-of-plane X-ray nanodiffraction. Journal of Applied Crystallography, 2018, 51, 1387-1395. | 4.5 | 11 |
| 9 | Coherent X-ray diffraction imaging meets ptychography to study core-shell-shell nanowires. MRS Advances, 2018, 3, 2317-2322. | 0.9 | 7 |
| 10 | Determination of indium content of $GaAs/(In,Ga)As/(GaAs)$ core-shell(-shell) nanowires by x-ray diffraction and nano x-ray fluorescence. Physical Review Materials, 2018, 2, . | 2.4 | 12 |
| 11 | Anomalous Strain Relaxation in Core–Shell Nanowire Heterostructures via Simultaneous Coherent and Incoherent Growth. Nano Letters, 2017, 17, 136-142. | 9.1 | 35 |
| 12 | Surface preparation and patterning by nano imprint lithography for the selective area growth of GaAs nanowires on Si(111). Semiconductor Science and Technology, 2017, 32, 115003. | 2.0 | 21 |
| 13 | Efficient methodology to correlate structural with optical properties of GaAs nanowires based on scanning electron microscopy. Nanotechnology, 2017, 28, 415703. | 2.6 | 7 |
| 14 | Self-Assembly of InAs Nanostructures on the Sidewalls of GaAs Nanowires Directed by a Bi Surfactant. Nano Letters, 2017, 17, 4255-4260. | 9.1 | 19 |
| 15 | Ga predeposition for the Ga-assisted growth of GaAs nanowire ensembles with low number density and homogeneous length. Journal of Crystal Growth, 2017, 459, 43-49. | 1.5 | 23 |
| 16 | Threefold rotational symmetry in hexagonally shaped core–shell (In,Ga)As/GaAs nanowires revealed by coherent X-ray diffraction imaging. Journal of Applied Crystallography, 2017, 50, 673-680. | 4.5 | 11 |
| 17 | Exciton recombination at crystal-phase quantum rings in GaAs/In <i>x</i> Galâ^' <i>x</i> As core/multishell nanowires. Applied Physics Letters, 2016, 109, . | 3.3 | 10 |
| 18 | Exciton dynamics in GaAs/(Al,Ga)As core-shell nanowires with shell quantum dots. Physical Review B, 2016, 94, . | 3.2 | 10 |

| # | Article | lF | CITATIONS |
|----|--|-----|-----------|
| 19 | Growth map for Ga-assisted growth of GaAs nanowires on Si(111) substrates by molecular beam epitaxy. Nanotechnology, 2016, 27, 095601. | 2.6 | 41 |